

# LMV716 5 MHz, Low Noise, RRO, Dual Operational Amplifier with CMOS Input

Check for Samples: [LMV716](#)

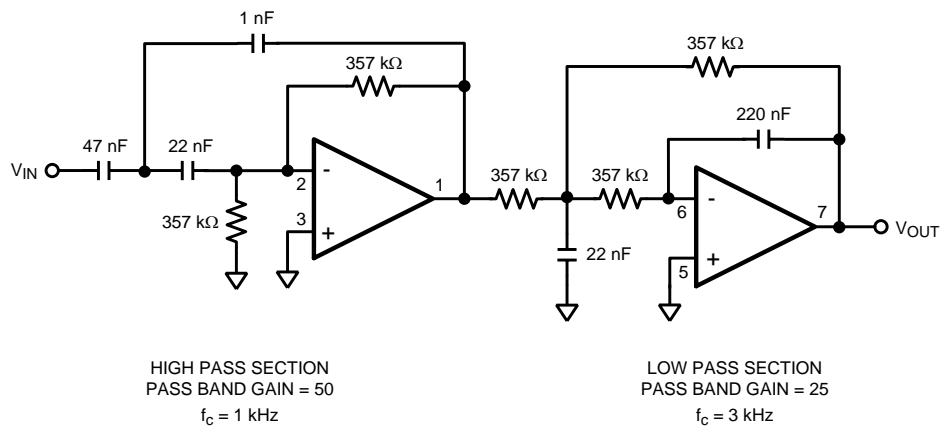
## FEATURES

- (Typical Values,  $V^+ = 3.3V$ ,  $T_A = 25^\circ C$ , unless Otherwise Specified)
- Input Noise Voltage  $12.8 \text{ nV}/\sqrt{\text{Hz}}$
- Input Bias Current  $0.6 \text{ pA}$
- Offset Voltage  $1.6 \text{ mV}$
- CMRR  $80 \text{ dB}$
- Open Loop Gain  $122 \text{ dB}$
- Rail-to-Rail Output
- GBW  $5 \text{ MHz}$
- Slew Rate  $5.8 \text{ V}/\mu\text{s}$
- Supply Current  $1.6 \text{ mA}$
- Supply Voltage Range  $2.7V$  to  $5V$
- Operating Temperature  $-40^\circ C$  to  $85^\circ C$
- 8-pin VSSOP Package

## APPLICATIONS

- Active Filters
- Transimpedance Amplifiers
- Audio Preamp
- HDD Vibration Cancellation Circuitry

## Typical Application Circuit


**Figure 1. High Gain Band Pass Filter**

## DESCRIPTION

The LMV716 is a dual operational amplifier with both low supply voltage and low supply current, making it ideal for portable applications. The LMV716 CMOS input stage drives the  $I_{BIAS}$  current down to  $0.6 \text{ pA}$ ; this coupled with the low noise voltage of  $12.8 \text{ nV}/\sqrt{\text{Hz}}$  makes the LMV716 perfect for applications requiring active filters, transimpedance amplifiers, and HDD vibration cancellation circuitry.

Along with great noise sensitivity, small signal applications will benefit from the large gain bandwidth of  $5 \text{ MHz}$  coupled with the minimal supply current of  $1.6 \text{ mA}$  and a slew rate of  $5.8 \text{ V}/\mu\text{s}$ .

The LMV716 provides rail-to-rail output swing into heavy loads. The input common-mode voltage range includes ground, which is ideal for ground sensing applications.

The LMV716 has a supply voltage spanning  $2.7V$  to  $5V$  and is offered in an 8-pin VSSOP package that functions across the wide temperature range of  $-40^\circ C$  to  $85^\circ C$ . This small package makes it possible to place the LMV716 next to sensors, thus reducing external noise pickup.



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### Absolute Maximum Ratings <sup>(1)(2)</sup>

ESD Tolerance <sup>(3)</sup>	
Human Body Model	2000V
Machine Model	200V
Supply Voltage (V <sup>+</sup> – V <sup>-</sup> )	5.5V
Storage Temperature Range	-65°C to 150°C
Junction Temperature <sup>(4)</sup>	150°C max
Mounting Temperature	
Infrared or Convection (20 sec)	260°C

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not ensured. For ensured specifications and the test conditions, see the Electrical Characteristics.
- (2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.
- (3) Human Body Model is 1.5 k $\Omega$  in series with 100 pF. Machine Model is 0 $\Omega$  in series with 100 pF.
- (4) The maximum power dissipation is a function of T<sub>J(MAX)</sub>,  $\theta_{JA}$  and T<sub>A</sub>. The maximum allowable power dissipation at any ambient temperature is  $P_D = (T_{J(MAX)} - T_A) / \theta_{JA}$ . All numbers apply for packages soldered directly into a PC board.

### Operating Ratings <sup>(1)</sup>

Supply Voltage	2.7V to 5V
Temperature Range	-40°C to 85°C
Thermal Resistance ( $\theta_{JA}$ )	
8-Pin VSSOP	195°C/W

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not ensured. For ensured specifications and the test conditions, see the Electrical Characteristics.

### 3.3V Electrical Characteristics <sup>(1)</sup>

Unless otherwise specified, all limits are ensured for  $T_J = 25^\circ\text{C}$ ,  $V^+ = 3.3\text{V}$ ,  $V^- = 0\text{V}$ .  $V_{\text{CM}} = V^+/2$ . **Boldface** limits apply at the temperature extremes <sup>(2)</sup>.

Symbol	Parameter	Condition	Min <sup>(3)</sup>	Typ <sup>(4)</sup>	Max <sup>(3)</sup>	Units
$V_{\text{OS}}$	Input Offset Voltage	$V_{\text{CM}} = 1\text{V}$		1.6	<b>5</b> <b>6</b>	mV
$I_{\text{B}}$	Input Bias Current	<sup>(5)</sup>		0.6	<b>115</b> <b>130</b>	pA
$I_{\text{OS}}$	Input Offset Current			1		pA
CMRR	Common Mode Rejection Ratio	$0 \leq V_{\text{CM}} \leq 2.1\text{V}$	<b>60</b> <b>50</b>	80		dB
PSRR	Power Supply Rejection Ratio	$2.7\text{V} \leq V^+ \leq 5\text{V}$ , $V_{\text{CM}} = 1\text{V}$	<b>70</b> <b>60</b>	82		dB
CMVR	Common Mode Voltage Range	For CMRR $\geq 50$ dB	-0.2		2.2	V
$A_{\text{VOL}}$	Open Loop Voltage Gain	Sourcing $R_{\text{L}} = 10\text{ k}\Omega$ to $V^+/2$ , $V_{\text{O}} = 1.65\text{V}$ to $2.9\text{V}$	<b>80</b> <b>76</b>	122		dB
		Sinking $R_{\text{L}} = 10\text{ k}\Omega$ to $V^+/2$ , $V_{\text{O}} = 0.4\text{V}$ to $1.65\text{V}$	<b>80</b> <b>76</b>	122		
		Sourcing $R_{\text{L}} = 600\Omega$ to $V^+/2$ , $V_{\text{O}} = 1.65\text{V}$ to $2.8\text{V}$	<b>80</b> <b>76</b>	105		
		Sinking $R_{\text{L}} = 600\Omega$ to $V^+/2$ , $V_{\text{O}} = 0.5\text{V}$ to $1.65\text{V}$	<b>80</b> <b>76</b>	112		
$V_{\text{O}}$	Output Swing High	$R_{\text{L}} = 10\text{ k}\Omega$ to $V^+/2$	<b>3.22</b> <b>3.17</b>	3.29		V
		$R_{\text{L}} = 600\Omega$ to $V^+/2$	<b>3.12</b> <b>3.07</b>	3.22		
	Output Swing Low	$R_{\text{L}} = 10\text{ k}\Omega$ to $V^+/2$		0.03	<b>0.12</b> <b>0.16</b>	
		$R_{\text{L}} = 600\Omega$ to $V^+/2$		0.07	<b>0.23</b> <b>0.27</b>	
$I_{\text{OUT}}$	Output Current	Sourcing, $V_{\text{O}} = 0\text{V}$	<b>20</b> <b>15</b>	31		mA
		Sinking, $V_{\text{O}} = 3.3\text{V}$	<b>30</b> <b>25</b>	41		
$I_{\text{S}}$	Supply Current	$V_{\text{CM}} = 1\text{V}$		1.6	<b>2.0</b> <b>3</b>	mA
SR	Slew Rate	<sup>(6)</sup>		5.8		V/ $\mu\text{s}$
GBW	Gain Bandwidth			5		MHz
$e_{\text{n}}$	Input-Referred Voltage Noise	$f = 1\text{ kHz}$		12.8		nV/ $\sqrt{\text{Hz}}$
$i_{\text{n}}$	Input-Referred Current Noise	$f = 1\text{ kHz}$		0.01		pA/ $\sqrt{\text{Hz}}$

(1) Electrical Table values apply only for factory testing conditions at the temperature indicated. Factor testing conditions result in very limited self-heating of the device such that  $T_J = T_A$ . No ensured specification of parametric performance is indicated in the electrical tables under conditions of internal self-heating where  $T_J > T_A$ . Absolute Maximum Ratings indicate junction temperature limits beyond which the device may be permanently degraded, either mechanically or electrically.

(2) Boldface limits apply to temperature range of  $-40^\circ\text{C}$  to  $85^\circ\text{C}$ .

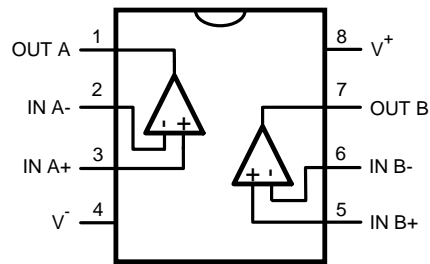
(3) All limits are specified by testing or statistical analysis.

(4) Typical values represent the most likely parametric norm.

(5) Input bias current is specified by design.

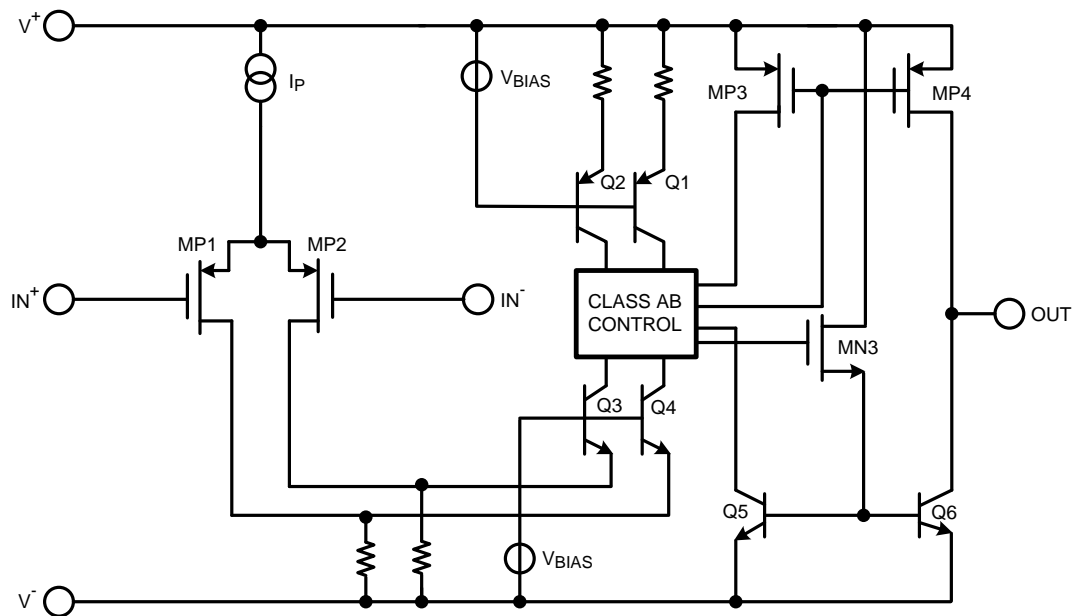
(6) Number specified is the lower of the positive and negative slew rates.

**CONNECTION DIAGRAM**



**Figure 2. Top View - 8-Pin VSSOP**

**Simplified Schematic**



### Typical Performance Characteristics

Unless otherwise specified,  $V^+ = 3.3V$ ,  $T_J = 25^\circ C$ .

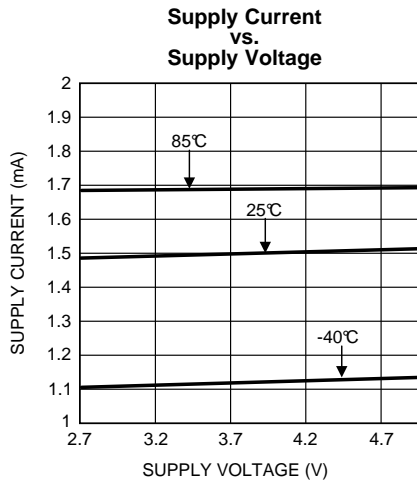


Figure 3.

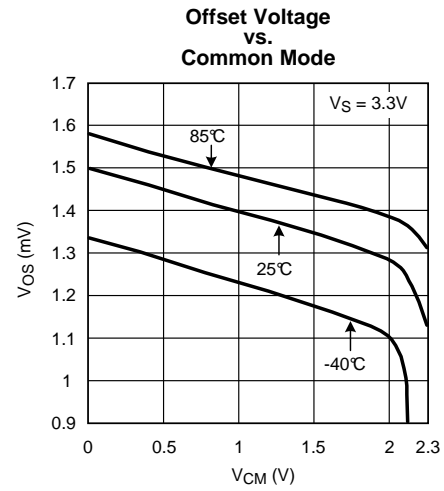


Figure 4.

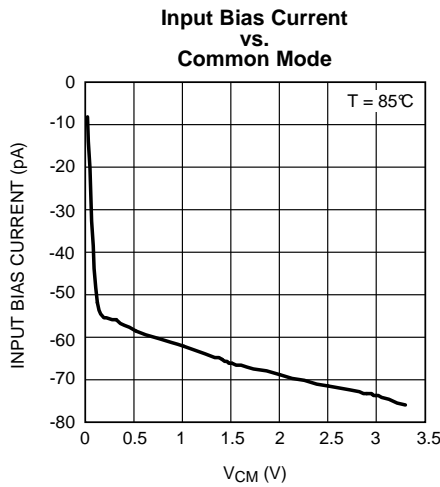


Figure 5.

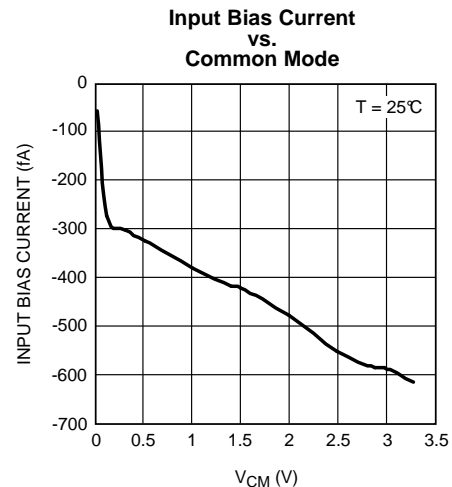


Figure 6.

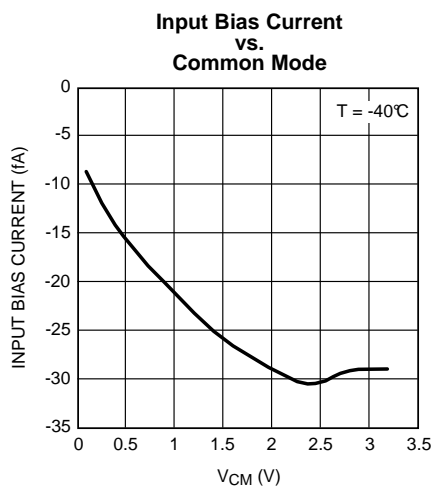


Figure 7.

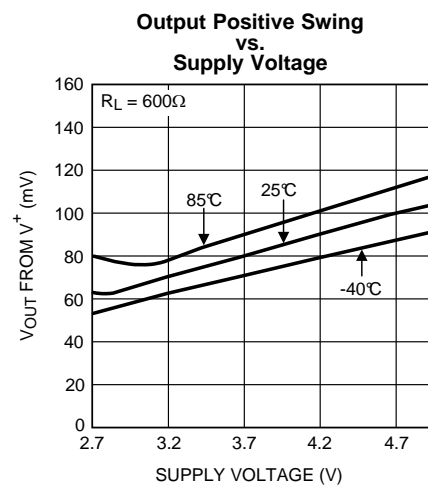


Figure 8.

**Typical Performance Characteristics (continued)**

Unless otherwise specified,  $V^+ = 3.3V$ ,  $T_J = 25^\circ C$ .

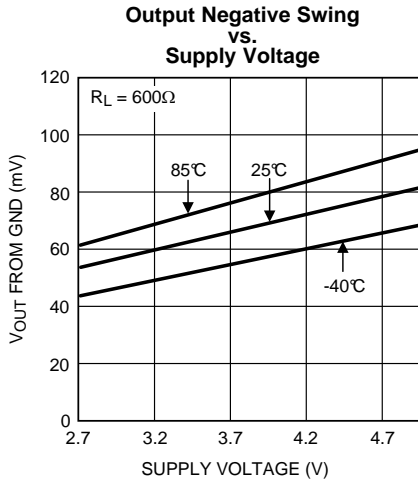


Figure 9.

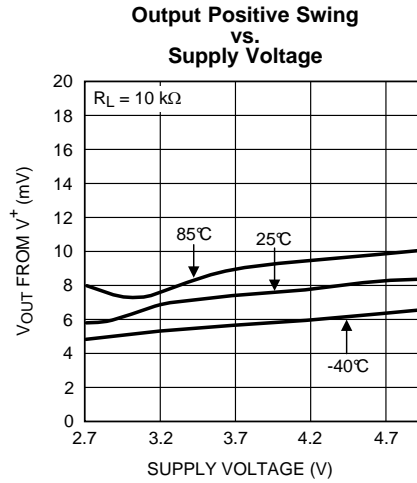


Figure 10.

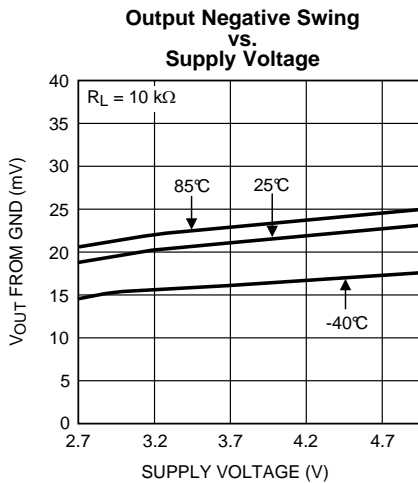


Figure 11.

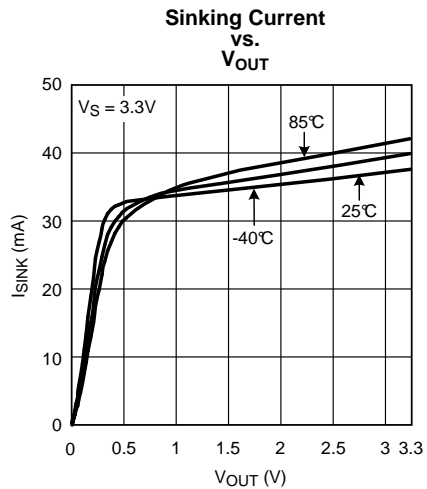


Figure 12.

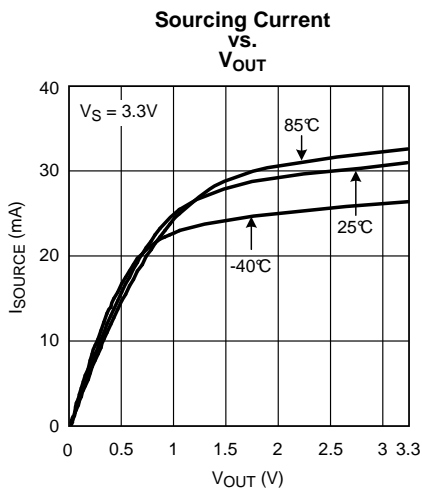


Figure 13.

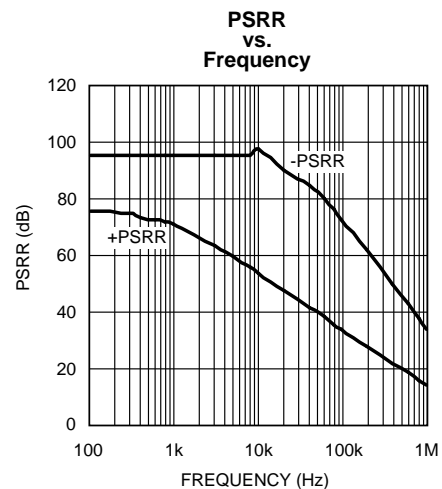


Figure 14.

**Typical Performance Characteristics (continued)**

Unless otherwise specified,  $V^+ = 3.3V$ ,  $T_J = 25^\circ C$ .

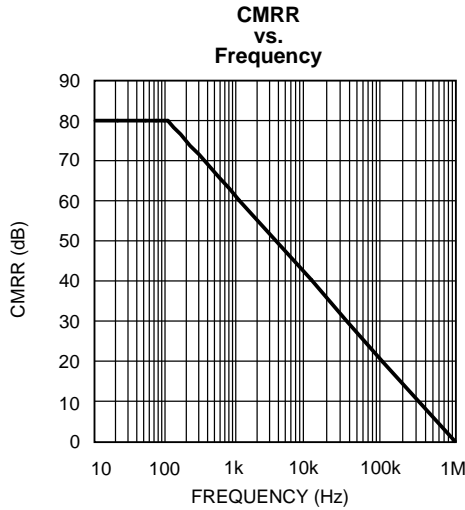


Figure 15.

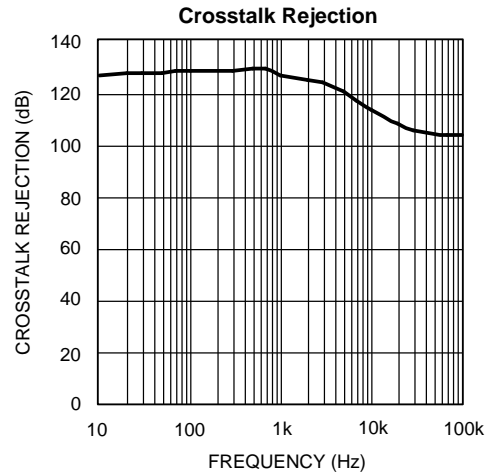


Figure 16.

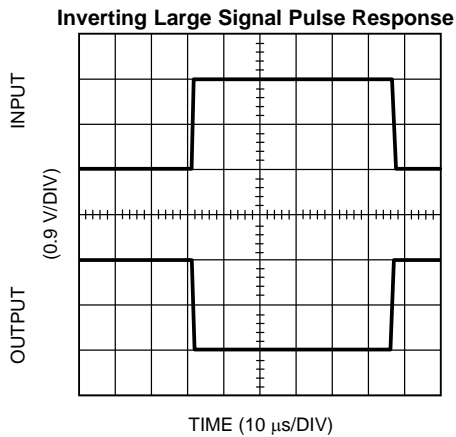


Figure 17.

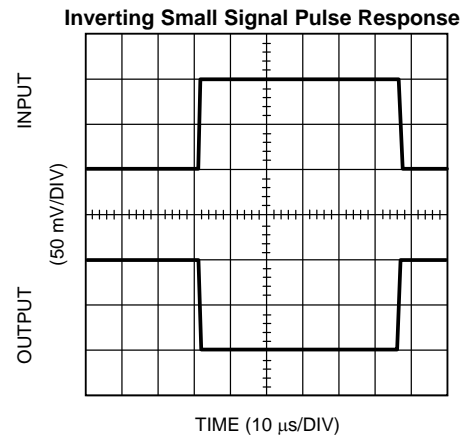


Figure 18.

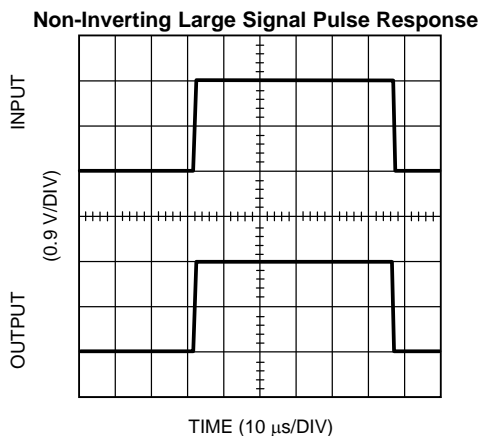


Figure 19.

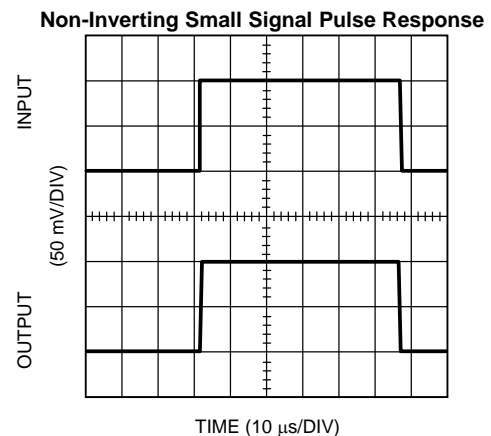


Figure 20.

**Typical Performance Characteristics (continued)**

Unless otherwise specified,  $V^+ = 3.3V$ ,  $T_J = 25^\circ C$ .

**Open Loop Frequency vs.  $R_L$**

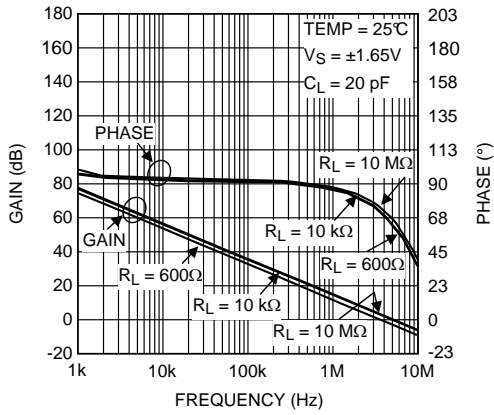


Figure 21.

**Open Loop Frequency Response over Temperature**

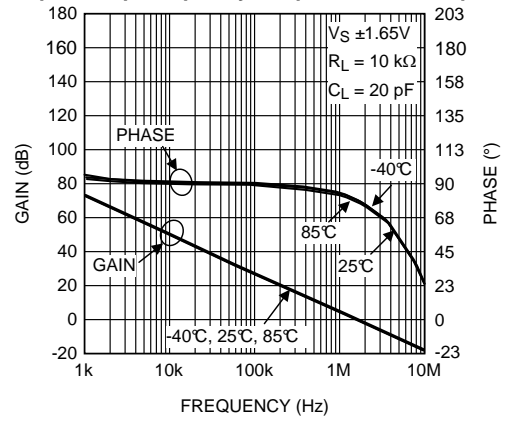


Figure 22.

**Open Loop Frequency Response vs.  $C_L$**

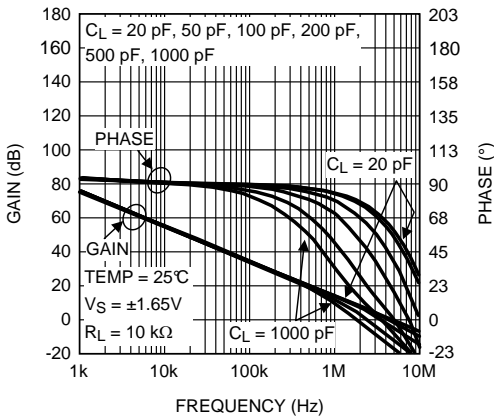


Figure 23.

**Open Loop Frequency Response vs.  $C_L$**

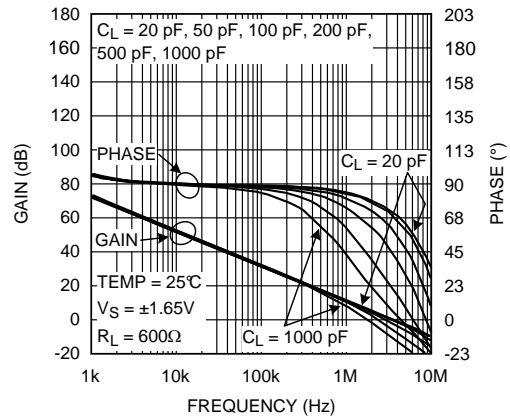


Figure 24.

**Voltage Noise vs. Frequency**

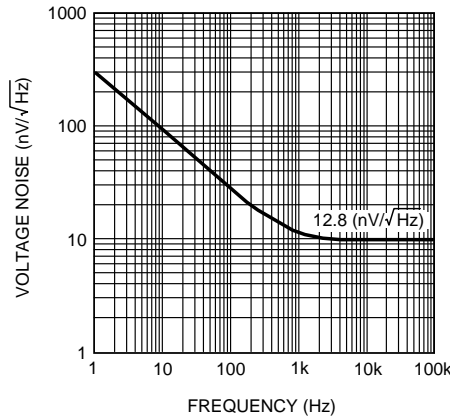


Figure 25.

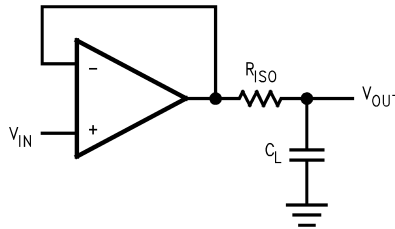


## APPLICATION INFORMATION

With the low supply current of only 1.6 mA, the LMV716 offers users the ability to maximize battery life. This makes the LMV716 ideal for battery powered systems. The LMV716's rail-to-rail output swing provides the maximum possible dynamic range at the output. This is particularly important when operating on low supply voltages.

### CAPACITIVE LOAD TOLERANCE

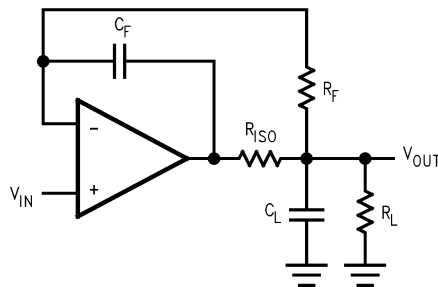
The LMV716, when in a unity-gain configuration, can directly drive large capacitive loads in unity-gain without oscillation. The unity-gain follower is the most sensitive configuration to capacitive loading; direct capacitive loading reduces the phase margin of amplifiers. The combination of the amplifier's output impedance and the capacitive load induces phase lag. This results in either an underdamped pulse response or oscillation. To drive a heavier capacitive load, the circuit in [Figure 26](#) can be used.



**Figure 26. Indirectly Driving a Capacitive Load using Resistive Isolation**

In [Figure 26](#), the isolation resistor  $R_{ISO}$  and the load capacitor  $C_L$  form a pole to increase stability by adding more phase margin to the overall system. The desired performance depends on the value of  $R_{ISO}$ . The bigger the  $R_{ISO}$  resistor value, the more stable  $V_{OUT}$  will be.

The circuit in [Figure 27](#) is an improvement to the one in [Figure 26](#) because it provides DC accuracy as well as AC stability. If there were a load resistor in [Figure 26](#), the output would be voltage divided by  $R_{ISO}$  and the load resistor. Instead, in [Figure 27](#),  $R_F$  provides the DC accuracy by using feed-forward techniques to connect  $V_{IN}$  to  $R_L$ . Due to the input bias current of the LMV716, the designer must be cautious when choosing the value of  $R_F$ .  $C_F$  and  $R_{ISO}$  serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving phase margin in the overall feedback loop. Increased capacitive drive is possible by increasing the value of  $C_F$ . This in turn will slow down the pulse response.



**Figure 27. Indirectly Driving a Capacitive Load with DC Accuracy**

## DIFFERENCE AMPLIFIER

The difference amplifier allows the subtraction of two voltages or, as a special case, the cancellation of a signal common to two inputs. It is useful as a computational amplifier in making a differential to single-ended conversion or in rejecting a common mode signal.

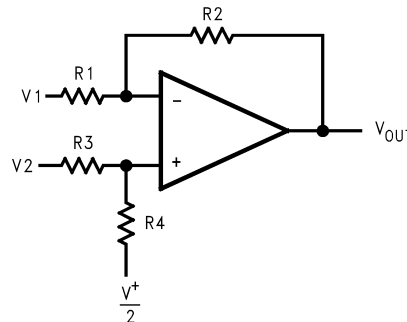


Figure 28. Difference Amplifier

$$V_{OUT} = \left( \frac{R1+R2}{R3+R4} \right) \frac{R4}{R1} V_2 - \frac{R2}{R1} V_1 + \left( \frac{R1+R2}{R3+R4} \right) \frac{R3}{R1} \cdot \frac{V^+}{2}$$

for  $R1 = R3$  and  $R2 = R4$

$$V_{OUT} = \frac{R2}{R1} (V_2 - V_1) + \frac{V^+}{2}$$

(1)

## SINGLE-SUPPLY INVERTING AMPLIFIER

There may be cases where the input signal going into the amplifier is negative. Because the amplifier is operating in single supply voltage, a voltage divider using  $R_3$  and  $R_4$  is implemented to bias the amplifier so the inverting input signal is within the input common voltage range of the amplifier. The capacitor  $C_1$  is placed between the inverting input and resistor  $R_1$  to block the DC signal going into the AC signal source,  $V_{IN}$ . The values of  $R_1$  and  $C_1$  affect the cutoff frequency,  $f_c = \frac{1}{2\pi R_1 C_1}$ . As a result, the output signal is centered around mid-supply (if the voltage divider provides  $V^+/2$  at the non-inverting input). The output can swing to both rails, maximizing the signal-to-noise ratio in a low voltage system.

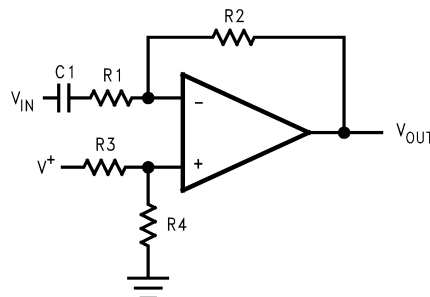


Figure 29. Single-supply Inverting Amplifier

$$V_{OUT} = -\frac{R2}{R1} V_{IN}$$

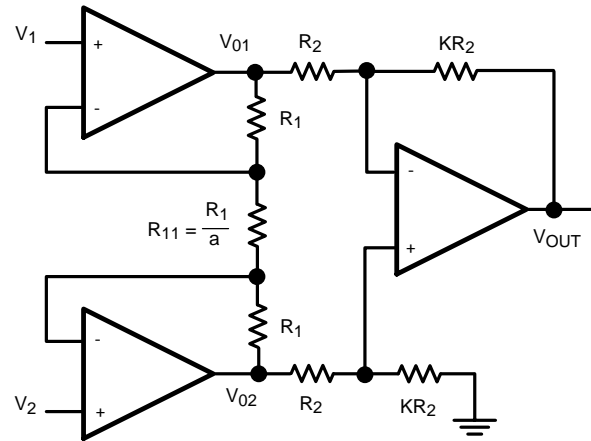
(2)

## INSTRUMENTATION AMPLIFIER

Measurement of very small signals with an amplifier requires close attention to the input impedance of the amplifier, the overall signal gain from both inputs to the output, as well as, the gain from each input to the output. This is because we are only interested in the difference of the two inputs and the common signal is considered noise. A classic solution is an instrumentation amplifier. Instrumentation amplifiers have a finite, accurate, and stable gain. Also they have extremely high input impedances and very low output impedances. Finally they have an extremely high CMRR so that the amplifier can only respond to the differential signal.

### Three-Op-Amp Instrumentation Amplifier

A typical instrumentation amplifier is shown in [Figure 30](#).



**Figure 30. Three-Op-Amp Instrumentation Amplifier**

There are two stages in this configuration. The last stage, the output stage, is a differential amplifier. In an ideal case the two amplifiers of the first stage, the input stage, would be set up as buffers to isolate the inputs. However they cannot be connected as followers due to the mismatch of real amplifiers. The circuit in [Figure 30](#) utilizes a balancing resistor between the two amplifiers to compensate for this mismatch. The product of the two stages of gain will be the gain of the instrumentation amplifier circuit. Ideally, the CMRR should be infinite. However the output stage has a small non-zero common mode gain which results from resistor mismatch.

In the input stage of the circuit, current is the same across all resistors. This is due to the high input impedance and low input bias current of the LMV716. With the node equations we have:

$$\text{GIVEN: } I_{R1} = I_{R11} \tag{3}$$

By Ohm's Law:

$$\begin{aligned} V_{O1} - V_{O2} &= (2R_1 + R_{11}) I_{R11} \\ &= (2a + 1) R_{11} \cdot I_{R11} \\ &= (2a + 1) V_{R11} \end{aligned} \tag{4}$$

However:

$$V_{R11} = V_1 - V_2 \tag{5}$$

So we have:

$$V_{O1} - V_{O2} = (2a + 1) (V_1 - V_2) \tag{6}$$

Now looking at the output of the instrumentation amplifier:

$$\begin{aligned} V_O &= \frac{KR_2}{R_2} (V_{O2} - V_{O1}) \\ &= -K (V_{O1} - V_{O2}) \end{aligned} \tag{7}$$

Substituting from [Equation 6](#):

$$V_O = -K (2a + 1) (V_1 - V_2) \tag{8}$$

This shows the gain of the instrumentation amplifier to be:

$$-K(2a+1) \quad (9)$$

Typical values for this circuit can be obtained by setting:  $a = 12$  and  $K = 4$ . This results in an overall gain of  $-100$ .

Three LMV716 amplifiers are used along with 1% resistors to minimize resistor mismatch. Resistors used to build the circuit are:  $R_1 = 21.6 \text{ k}\Omega$ ,  $R_{11} = 1.8 \text{ k}\Omega$ ,  $R_2 = 2.5 \text{ k}\Omega$  with  $K = 40$  and  $a = 12$ . This results in an overall gain of  $-K(2a+1) = -1000$ .

### Two-Op-Amp Instrumentation Amplifier

A two-op-amp instrumentation amplifier can also be used to make a high-input impedance DC differential amplifier (Figure 31). As in the three op amp circuit, this instrumentation amplifier requires precise resistor matching for good CMRR.  $R_4$  should be equal to  $R_1$ , and  $R_3$  should equal  $R_2$ .

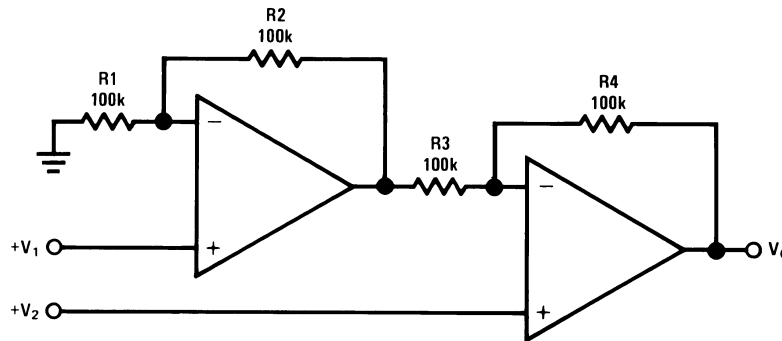


Figure 31. Two-Op-Amp Instrumentation Amplifier

$$V_0 = \left(1 + \frac{R_4}{R_3}\right)(V_2 - V_1), \text{ where } R_1 = R_4 \text{ and } R_2 = R_3$$

$$\text{As shown: } V_0 = 2(V_2 - V_1) \quad (10)$$

## ACTIVE FILTERS

Active filters are circuits with amplifiers, resistors, and capacitors. The use of amplifiers instead of inductors, which are used in passive filters, enhances the circuit performance while reducing the size and complexity of the filter. The simplest active filters are designed using an inverting op amp configuration where at least one reactive element has been added to the configuration. This means that the op amp will provide "frequency-dependent" amplification, since reactive elements are frequency dependent devices.

### Low Pass Filter

The following shows a very simple low pass filter.

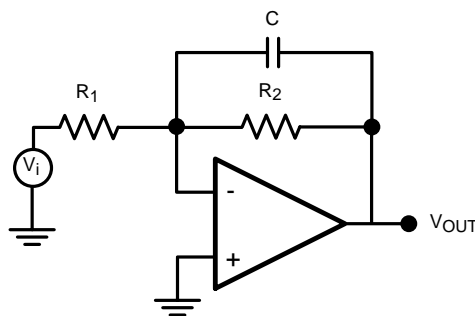


Figure 32. Low Pass Filter

The transfer function can be expressed as follows:

By KCL:

$$\frac{-V_i}{R_1} - \frac{V_O}{\left[ \frac{1}{j\omega C} \right]} - \frac{V_O}{R_2} = 0 \quad (11)$$

Simplifying this further results in:

$$V_O = \frac{-R_2}{R_1} \left[ \frac{1}{j\omega C R_2 + 1} \right] V_i \quad (12)$$

or

$$\frac{V_O}{V_i} = \frac{-R_2}{R_1} \left[ \frac{1}{j\omega C R_2 + 1} \right] \quad (13)$$

Now, substituting  $\omega = 2\pi f$ , so that the calculations are in  $f(\text{Hz})$  rather than in  $\omega(\text{rad/s})$ , and setting the DC gain

$$\left[ \frac{-R_2}{R_1} = H_0 \right] \text{ and } H = \frac{V_O}{V_i}$$

$$H = H_0 \left[ \frac{1}{j2\pi f C R_2 + 1} \right] \quad (14)$$

$$f_0 = \frac{1}{2\pi R_1 C}$$

set:

$$H = H_0 \left[ \frac{1}{1 + j(f/f_0)} \right] \quad (15)$$

Low pass filters are known as lossy integrators because they only behave as integrators at higher frequencies. The general form of the bode plot can be predicted just by looking at the transfer function. When the  $f/f_0$  ratio is small, the capacitor is, in effect, an open circuit and the amplifier behaves at a set DC gain. Starting at  $f_0$ , which is the  $-3 \text{ dB}$  corner, the capacitor will have the dominant impedance and hence the circuit will behave as an integrator and the signal will be attenuated and eventually cut. The bode plot for this filter is shown in [Figure 33](#).

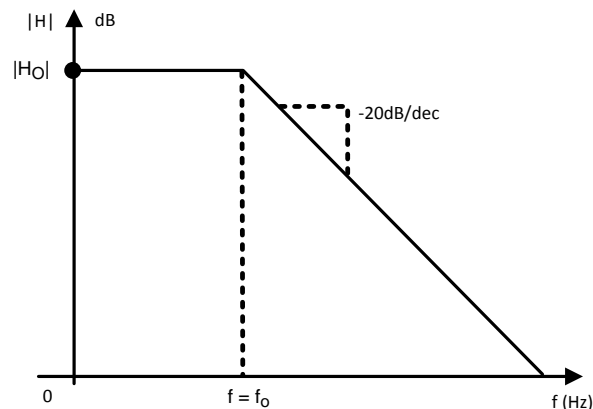
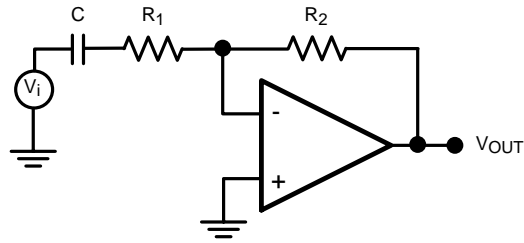


Figure 33. Low Pass Filter Transfer Function

## High Pass Filter

The transfer function of a high pass filter can be derived in much the same way as the previous example. A typical first order high pass filter is shown below:



**Figure 34. High Pass Filter**

Writing the KCL for this circuit :

( $V_1$  denotes the voltage between C and  $R_1$ )

$$\frac{V_1 - V_i}{\frac{1}{j\omega C}} = \frac{V_1 - V^-}{R_1} \quad (16)$$

$$\frac{V^- + V_1}{R_1} = \frac{V^- + V_O}{R_2} \quad (17)$$

Solving these two equations to find the transfer function and using:

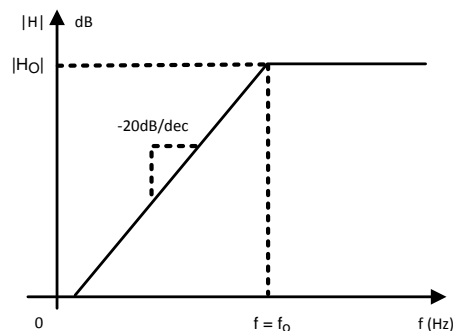
$$f_0 = \frac{1}{2\pi R_1 C} \quad (18)$$

(high frequency gain)  $H_0 = \frac{-R_2}{R_1}$  and  $H = \frac{V_O}{V_i}$

Which gives:

$$H = H_0 \frac{j(f/f_0)}{1 + j(f/f_0)} \quad (19)$$

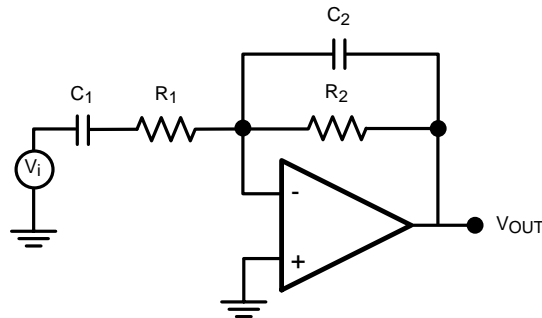
Looking at the transfer function, it is clear that when  $f/f_0$  is small, the capacitor is open and therefore, no signal is getting to the amplifier. As the frequency increases the amplifier starts operating. At  $f = f_0$  the capacitor behaves like a short circuit and the amplifier will have a constant, high frequency gain of  $H_0$ . Figure 35 shows the transfer function of this high pass filter.



**Figure 35. High Pass Filter Transfer Function**

### Band Pass Filter

Combining a low pass filter and a high pass filter will generate a band pass filter. [Figure 36](#) offers an example of this type of circuit.



**Figure 36. Band Pass Filter**

In this network the input impedance forms the high pass filter while the feedback impedance forms the low pass filter. If the designer chooses the corner frequencies so that  $f_1 < f_2$ , then all the frequencies between,  $f_1 \leq f \leq f_2$ , will pass through the filter while frequencies below  $f_1$  and above  $f_2$  will be cut off.

The transfer function can be easily calculated using the same methodology as before and is shown in [Figure 37](#).

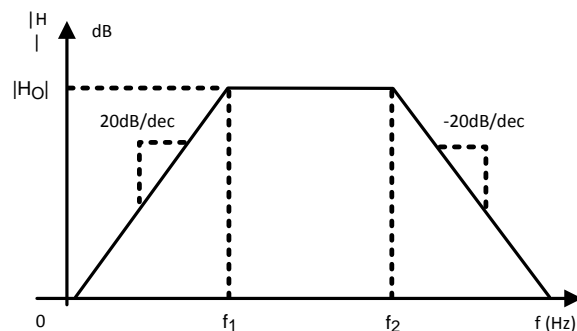
$$H = H_0 \frac{j(f/f_1)}{[1 + j(f/f_1)] [1 + j(f/f_2)]} \quad (20)$$

Where

$$f_1 = \frac{1}{2\pi R_1 C_1}$$

$$f_2 = \frac{1}{2\pi R_2 C_2}$$

$$H_0 = \frac{-R_2}{R_1} \quad (21)$$



**Figure 37. Band Pass Filter Transfer Function**

### STATE VARIABLE ACTIVE FILTER

State variable active filters are circuits that can simultaneously represent high pass, band pass, and low pass filters. The state variable active filter uses three separate amplifiers to achieve this task. A typical state variable active filter is shown in [Figure 38](#). The first amplifier in the circuit is connected as a gain stage. The second and third amplifiers are connected as integrators, which means they behave as low pass filters. The feedback path from the output of the third amplifier to the first amplifier enables this low frequency signal to be fed back with a

finite and fairly low closed loop gain. This is while the high frequency signal on the input is still gained up by the open loop gain of the first amplifier. This makes the first amplifier a high pass filter. The high pass signal is then fed into a low pass filter. The outcome is a band pass signal, meaning the second amplifier is a band pass filter. This signal is then fed into the third amplifiers input and so, the third amplifier behaves as a simple low pass filter.

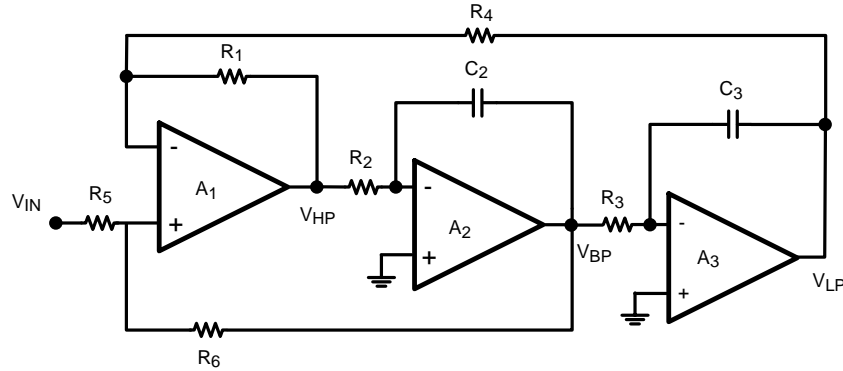
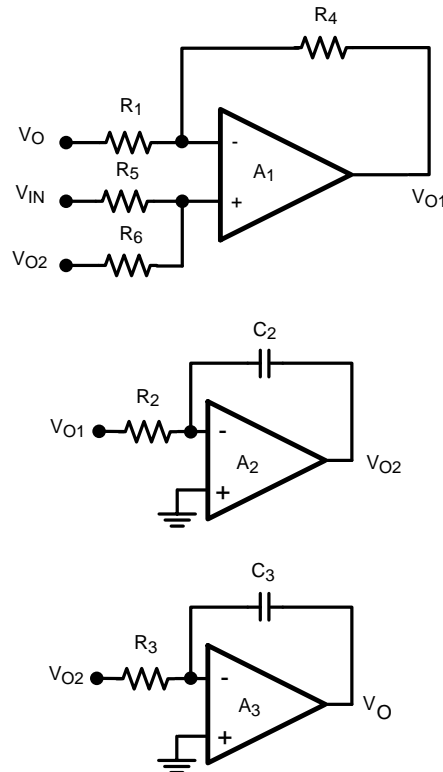


Figure 38. State Variable Active Filter

The transfer function of each filter needs to be calculated. The derivations will be more trivial if each stage of the filter is shown on its own.

The three components are:



For A<sub>1</sub> the relationship between input and output is:

$$V_{O1} = \frac{-R_4}{R_1} V_0 + \left[ \frac{R_6}{R_5 + R_6} \right] \left[ \frac{R_1 + R_4}{R_1} \right] V_{IN} + \left[ \frac{R_5}{R_5 + R_6} \right] \left[ \frac{R_1 + R_4}{R_1} \right] V_{O2} \tag{22}$$



This relationship depends on the output of all the filters. The input-output relationship for  $A_2$  can be expressed as:

$$V_{O2} = \frac{-1}{s C_2 R_2} V_{O1} \quad (23)$$

And finally this relationship for  $A_3$  is as follows:

$$V_O = \frac{-1}{s C_3 R_3} V_{O2} \quad (24)$$

Re-arranging these equations, one can find the relationship between  $V_O$  and  $V_{IN}$  (transfer function of the low pass filter),  $V_{O1}$  and  $V_{IN}$  (transfer function of the high pass filter), and  $V_{O2}$  and  $V_{IN}$  (transfer function of the band pass filter) These relationships are as follows:

### Low Pass Filter

$$\frac{V_O}{V_{IN}} = \frac{\left[ \frac{R_1 + R_4}{R_1} \right] \left[ \frac{R_6}{R_5 + R_6} \right] \left[ \frac{1}{C_2 C_3 R_2 R_3} \right]}{s^2 + s \left[ \frac{1}{C_2 R_2} \right] \left[ \frac{R_5}{R_5 + R_6} \right] \left[ \frac{R_1 + R_4}{R_1} \right] + \left[ \frac{1}{C_2 C_3 R_2 R_3} \right]} \quad (25)$$

(26)

### High Pass Filter

$$\frac{V_{O1}}{V_{IN}} = \frac{s^2 \left[ \frac{R_1 + R_4}{R_1} \right] \left[ \frac{R_6}{R_5 + R_6} \right]}{s^2 + s \left[ \frac{1}{C_2 R_2} \right] \left[ \frac{R_5}{R_5 + R_6} \right] \left[ \frac{R_1 + R_4}{R_1} \right] + \left[ \frac{1}{C_2 C_3 R_2 R_3} \right]} \quad (27)$$

### Band Pass Filter

$$\frac{V_{O2}}{V_{IN}} = \frac{s \left[ \frac{1}{C_2 R_2} \right] \left[ \frac{R_1 + R_4}{R_1} \right] \left[ \frac{R_6}{R_5 + R_6} \right]}{s^2 + s \left[ \frac{1}{C_2 R_2} \right] \left[ \frac{R_5}{R_5 + R_6} \right] \left[ \frac{R_1 + R_4}{R_1} \right] + \left[ \frac{1}{C_2 C_3 R_2 R_3} \right]} \quad (28)$$

The center frequency and Quality Factor for all of these filters is the same. The values can be calculated in the following manner:

$$\omega_c = \sqrt{\frac{1}{C_2 C_3 R_2 R_3}}$$

and

$$Q = \sqrt{\frac{C_2 R_2}{C_3 R_3} \left[ \frac{R_5 + R_6}{R_6} \right] \left[ \frac{R_1}{R_1 + R_4} \right]} \quad (29)$$

Designing a band pass filter with a center frequency of 10 kHz and Quality Factor of 5.5

To do this, first consider the Quality Factor. It is best to pick convenient values for the capacitors.  $C_2 = C_3 = 1000$  pF. Also, choose  $R_1 = R_4 = 30$  k $\Omega$ . Now values of  $R_5$  and  $R_6$  need to be calculated. With the chosen values for the capacitors and resistors, Q reduces to:

$$Q = \frac{11}{2} = \frac{1}{2} \left[ \frac{R_5 + R_6}{R_6} \right] \quad (30)$$

or

$$R_5 = 10R_6 \quad R_6 = 1.5 \text{ k}\Omega \quad R_5 = 15 \text{ k}\Omega \quad (31)$$

Also, for  $f = 10 \text{ kHz}$ , the center frequency is  $\omega c = 2\pi f = 62.8 \text{ kHz}$ .

Using the expressions above, the appropriate resistor values will be  $R_2 = R_3 = 16 \text{ k}\Omega$ .

The DC gain of this circuit is:

$$\text{DC GAIN} = \left[ \frac{R_1 + R_4}{R_1} \right] \left[ \frac{R_6}{R_5 + R_6} \right] = -14.8 \text{ dB} \quad (32)$$

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**REVISION HISTORY**

<b>Changes from Revision A (March 2013) to Revision B</b>	<b>Page</b>
• Changed layout of National Data Sheet to TI format .....	<a href="#">18</a>

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**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LMV716MM/NOPB	ACTIVE	VSSOP	DGK	8	1000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 85	AR3A	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSELETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

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(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMV716MM/NOPB	VSSOP	DGK	8	1000	178.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMV716MM/NOPB	VSSOP	DGK	8	1000	208.0	191.0	35.0

DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
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  - B. This drawing is subject to change without notice.
  - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
  - D. Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
  - E. Falls within JEDEC MO-187 variation AA, except interlead flash.



- NOTES:
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  - B. This drawing is subject to change without notice.
  - C. Publication IPC-7351 is recommended for alternate designs.
  - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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